



# SGM8250-1/SGM8250-2

## High Voltage, Micro-Power, Zero-Drift, CMOS Operational Amplifiers

---

### GENERAL DESCRIPTION

The single SGM8250-1 and dual SGM8250-2 CMOS operational amplifiers provide very low offset voltage and zero-drift over time and temperature.

The miniature, high precision, low quiescent current amplifiers offer high-impedance inputs that have a wide input common mode range of 100mV beyond the rails and rail-to-rail output that swings within 65mV of the rails. Single or dual supplies as low as 3V ( $\pm 1.5V$ ) and up to 24V ( $\pm 12V$ ) may be used. They are optimized for wide power supply range operation.

The single SGM8250-1 is available in Green SOT-23-5, SC70-5 and SOIC-8 packages. The dual SGM8250-2 is available in Green TDFN-3 $\times$ 3-8L and SOIC-8 packages. They are specified over  $-40^{\circ}C$  to  $+125^{\circ}C$  temperature range.

### FEATURES

- **Low Offset Voltage: 50 $\mu$ V (MAX)**
- **Low 0.1Hz to 10Hz Noise: 0.85 $\mu$ V<sub>P-P</sub>**
- **Quiescent Current: 50 $\mu$ A/Amplifier (TYP)**
- **Single or Dual Supply Operation**
- **Supply Voltage Range: 3V to 24V**
- **Rail-to-Rail Input and Output**
- **$-40^{\circ}C$  to  $+125^{\circ}C$  Operating Temperature Range**
- **Small Packaging:**
  - SGM8250-1 Available in Green SOT-23-5, SC70-5 and SOIC-8 Packages**
  - SGM8250-2 Available in Green TDFN-3 $\times$ 3-8L and SOIC-8 Packages**

### APPLICATIONS

Transducer Applications  
Temperature Measurements  
Electronic Scales  
Medical Instrumentation  
Battery-Powered Instruments  
Handheld Test Equipment

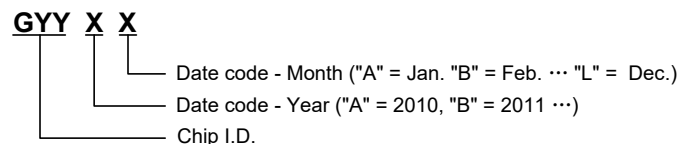
**PACKAGE/ORDERING INFORMATION**

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
SGM8250-1	SOT-23-5	-40°C to +125°C	SGM8250-1XN5G/TR	GSCXX	Tape and Reel, 3000
	SC70-5	-40°C to +125°C	SGM8250-1XC5G/TR	GS3XX	Tape and Reel, 3000
	SOIC-8	-40°C to +125°C	SGM8250-1XS8G/TR	SGM 82501XS8 XXXXX	Tape and Reel, 4000
SGM8250-2	TDFN-3×3-8L	-40°C to +125°C	SGM8250-2XTDB8G/TR	SGM 82502DB XXXXX	Tape and Reel, 4000
	SOIC-8	-40°C to +125°C	SGM8250-2XS8G/TR	SGM 82502XS8 XXXXX	Tape and Reel, 4000

NOTE: XX = Date Code. XXXXX = Date Code and Vendor Code.

Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

**MARKING INFORMATION**



For example: GSCHA (2017, January)

**ABSOLUTE MAXIMUM RATINGS**

Supply Voltage.....	26.4V
Input Common Mode Voltage Range .....	(-V <sub>S</sub> ) - 0.3V to (+V <sub>S</sub> ) + 0.3V
Junction Temperature.....	+150°C
Storage Temperature Range .....	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+260°C
ESD Susceptibility	
HBM.....	8000V
MM.....	250V
CDM .....	1000V

**RECOMMENDED OPERATING CONDITIONS**

Specified Voltage Range .....	3V to 24V
Operating Temperature Range .....	-40°C to +125°C

**OVERSTRESS CAUTION**

Stresses beyond those listed may cause permanent damage to the device. Functional operation of the device at these or any other conditions beyond those indicated in the operational section of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect reliability.

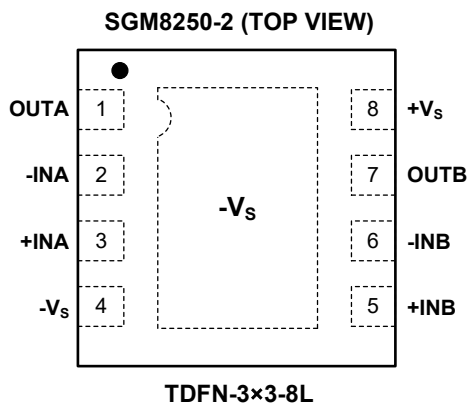
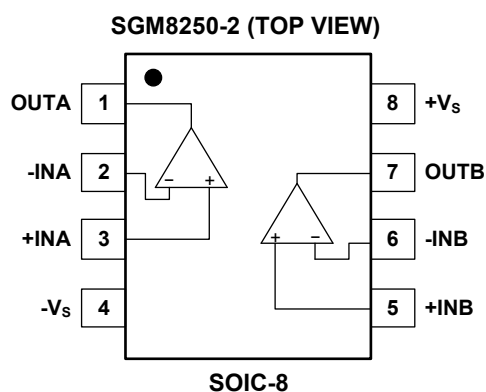
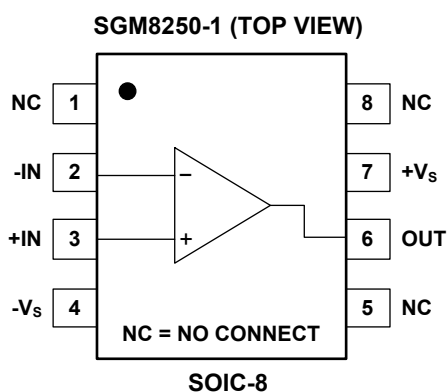
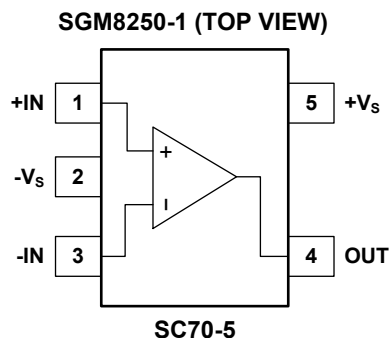
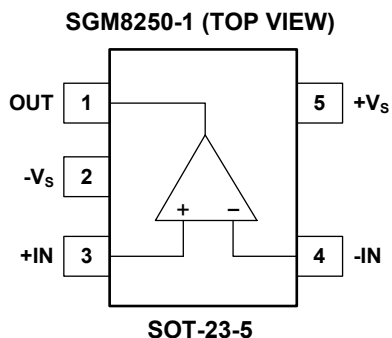
**ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

**DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, specification or other related things if necessary without notice at any time.

**PIN CONFIGURATIONS**



**ELECTRICAL CHARACTERISTICS**

(At  $T_A = +25^\circ\text{C}$ ,  $+V_S = 5\text{V}$ ,  $-V_S = 0\text{V}$ ,  $V_{CM} = +V_S/2$ ,  $V_{OUT} = +V_S/2$  and  $R_L = 10\text{k}\Omega$  to  $+V_S/2$ , Full =  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.)

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>INPUT CHARACTERISTICS</b>						
Input Offset Voltage ( $V_{OS}$ )		+25°C		10	50	$\mu\text{V}$
		Full			90	
Input Offset Voltage Drift ( $\Delta V_{OS}/\Delta T$ )		Full		0.11		$\mu\text{V}/^\circ\text{C}$
Input Bias Current ( $I_B$ )		+25°C		60		$\text{pA}$
Input Common Mode Voltage Range ( $V_{CM}$ )		Full	$(-V_S) - 0.1$		$(+V_S) + 0.1$	$\text{V}$
Common Mode Rejection Ratio (CMRR)	$(-V_S) - 0.1\text{V} < V_{CM} < (+V_S) + 0.1\text{V}$	+25°C	95	112		$\text{dB}$
		Full	92			
Open-Loop Voltage Gain ( $A_{OL}$ )	$(-V_S) + 0.1\text{V} < V_{OUT} < (+V_S) - 0.1\text{V}$	+25°C	108	131		$\text{dB}$
		Full	105			
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage Swing from Rail	$V_{OH}$	+25°C		14	25	$\text{mV}$
		Full			30	
	$V_{OL}$	+25°C		8	16	
		Full			20	
Output Short-Circuit Current ( $I_{SC}$ )		+25°C		$\pm 17$		$\text{mA}$
<b>POWER SUPPLY</b>						
Operating Voltage Range ( $V_S$ )		Full	3		24	$\text{V}$
Quiescent Current/Amplifier ( $I_Q$ )	$I_{OUT} = 0$	+25°C		45	60	$\mu\text{A}$
		Full			80	
Power Supply Rejection Ratio (PSRR)	$V_S = 3\text{V to } 24\text{V}$	+25°C	116	142		$\text{dB}$
		Full	113			
<b>DYNAMIC PERFORMANCE</b>						
Gain-Bandwidth Product (GBP)	$G = +100, C_L = 100\text{pF}$	+25°C		350		$\text{kHz}$
Slew Rate (SR)	$G = +1, V_{OUT} = 2V_{P-P}, C_L = 100\text{pF}$	+25°C		0.1		$\text{V}/\mu\text{s}$
Turn-On Time		+25°C		0.75		$\text{ms}$
<b>NOISE</b>						
Input Voltage Noise	$f = 0.1\text{Hz to } 10\text{Hz}$	+25°C		0.85		$\mu\text{V}_{P-P}$
Input Voltage Noise Density ( $e_n$ )	$f = 1\text{kHz}$	+25°C		40		$\text{nV}/\sqrt{\text{Hz}}$

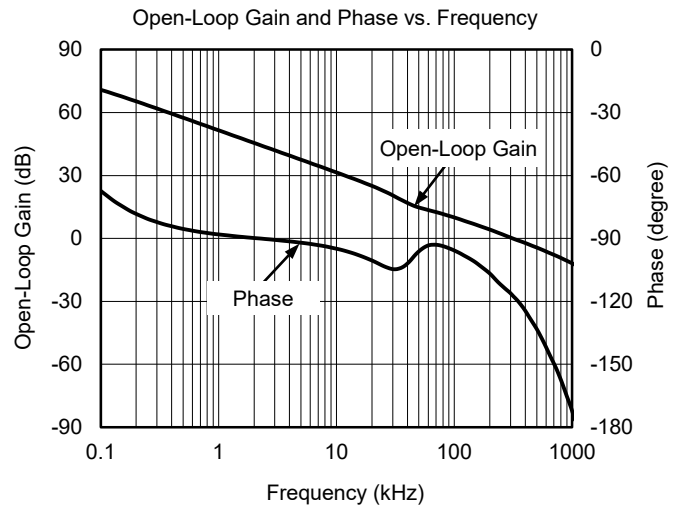
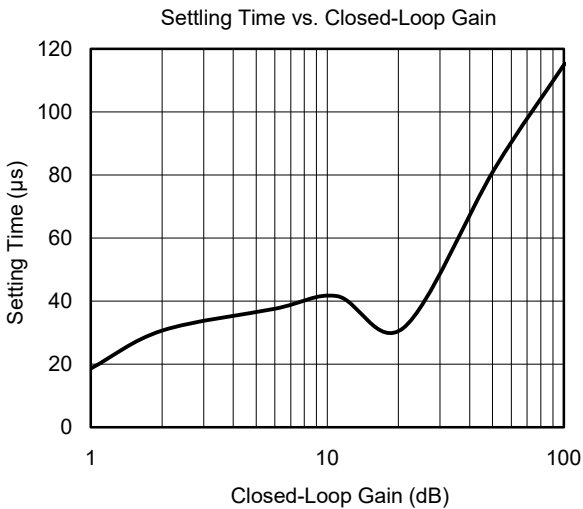
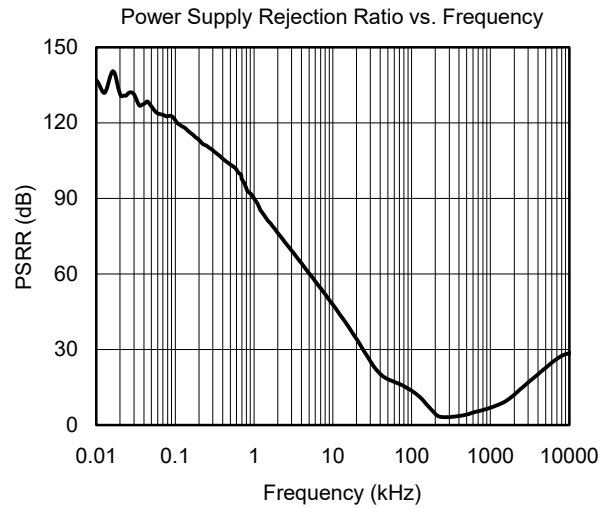
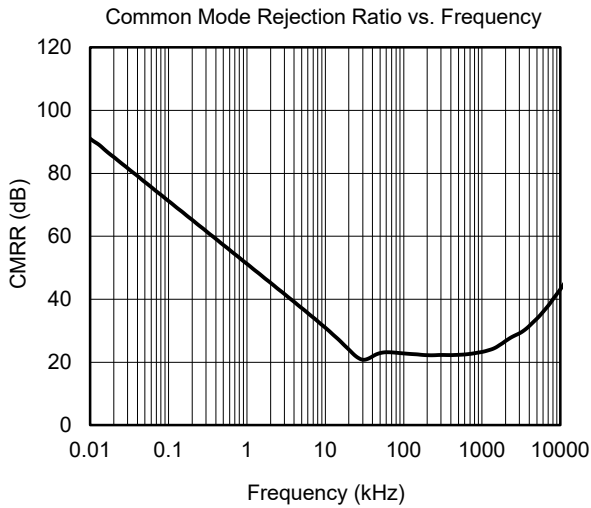
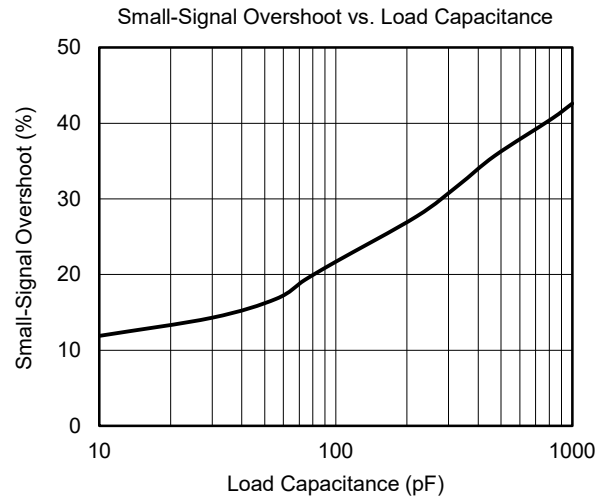
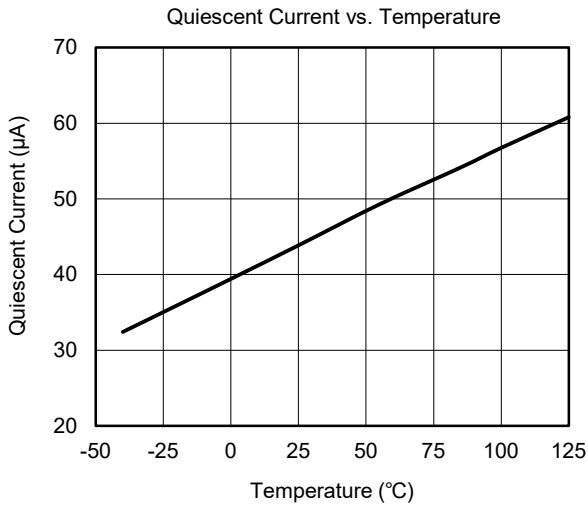
**ELECTRICAL CHARACTERISTICS (continued)**

(At  $T_A = +25^\circ\text{C}$ ,  $+V_S = 24\text{V}$ ,  $-V_S = 0\text{V}$ ,  $V_{CM} = +V_S/2$ ,  $V_{OUT} = +V_S/2$  and  $R_L = 10\text{k}\Omega$  to  $+V_S/2$ , Full =  $-40^\circ\text{C}$  to  $+125^\circ\text{C}$ , unless otherwise noted.)

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
<b>INPUT CHARACTERISTICS</b>						
Input Offset Voltage ( $V_{OS}$ )		+25°C		10	50	$\mu\text{V}$
		Full			90	
Input Offset Voltage Drift ( $\Delta V_{OS}/\Delta T$ )		Full		0.11		$\mu\text{V}/^\circ\text{C}$
Input Bias Current ( $I_B$ )		+25°C		80	850	$\text{pA}$
Input Common Mode Voltage Range ( $V_{CM}$ )		Full	$(-V_S) - 0.1$		$(+V_S) + 0.1$	$\text{V}$
Common Mode Rejection Ratio (CMRR)	$(-V_S) - 0.1\text{V} < V_{CM} < (+V_S) + 0.1\text{V}$	+25°C	112	130		$\text{dB}$
		Full	107			
Open-Loop Voltage Gain ( $A_{OL}$ )	$(-V_S) + 0.1\text{V} < V_{OUT} < (+V_S) - 0.1\text{V}$	+25°C	120	145		$\text{dB}$
		Full	110			
<b>OUTPUT CHARACTERISTICS</b>						
Output Voltage Swing from Rail	$V_{OH}$	+25°C		65	95	$\text{mV}$
		Full			130	
	$V_{OL}$	+25°C		37	60	
		Full			85	
Output Short-Circuit Current ( $I_{SC}$ )		+25°C		$\pm 17$		$\text{mA}$
<b>POWER SUPPLY</b>						
Operating Voltage Range ( $V_S$ )		Full	3		24	$\text{V}$
Quiescent Current/Amplifier ( $I_Q$ )	$I_{OUT} = 0$	+25°C		50	64	$\mu\text{A}$
		Full			84	
Power Supply Rejection Ratio (PSRR)	$V_S = 3\text{V to } 24\text{V}$	+25°C	116	142		$\text{dB}$
		Full	113			
<b>DYNAMIC PERFORMANCE</b>						
Gain-Bandwidth Product (GBP)	$G = +100, C_L = 100\text{pF}$	+25°C		350		$\text{kHz}$
Slew Rate (SR)	$G = +1, V_{OUT} = 2V_{P-P}, C_L = 100\text{pF}$	+25°C		0.09		$\text{V}/\mu\text{s}$
Turn-On Time		+25°C		1.5		$\text{ms}$
<b>NOISE</b>						
Input Voltage Noise	$f = 0.1\text{Hz to } 10\text{Hz}$	+25°C		0.85		$\mu\text{V}_{P-P}$
Input Voltage Noise Density ( $e_n$ )	$f = 1\text{kHz}$	+25°C		40		$\text{nV}/\sqrt{\text{Hz}}$

**TYPICAL PERFORMANCE CHARACTERISTICS**

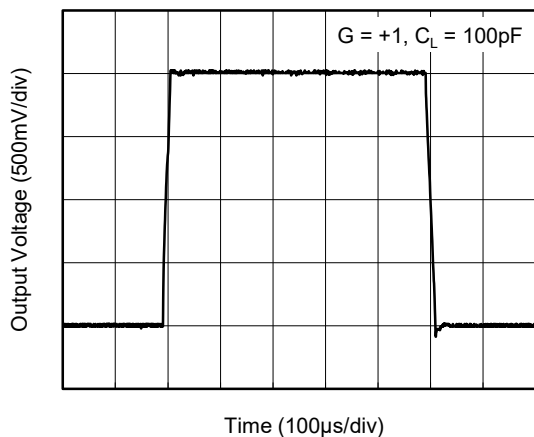
At  $T_A = +25^\circ\text{C}$ ,  $+V_S = 5\text{V}$ ,  $-V_S = 0\text{V}$ ,  $R_L = 10\text{k}\Omega$  and  $C_L = 0\text{pF}$ , unless otherwise noted.



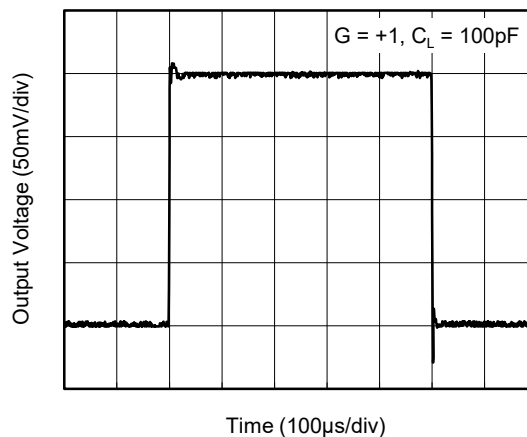
**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $+V_S = 5\text{V}$ ,  $-V_S = 0\text{V}$ ,  $R_L = 10\text{k}\Omega$  and  $C_L = 0\text{pF}$ , unless otherwise noted.

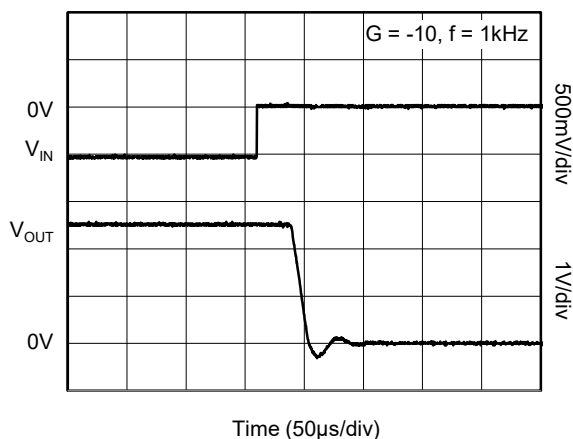
Large-Signal Step Response



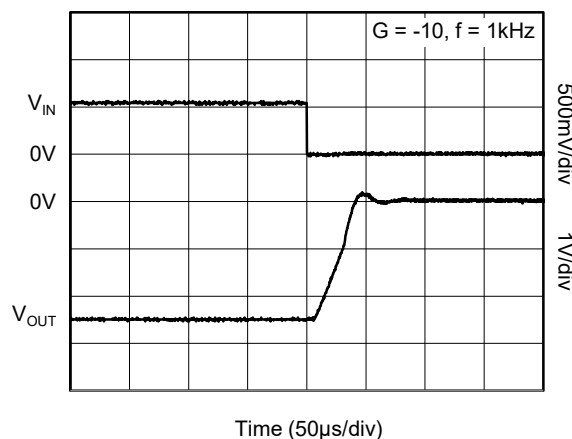
Small-Signal Step Response



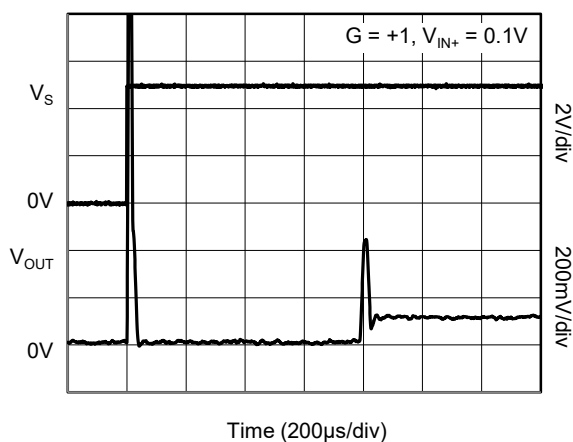
Positive Overload Recovery



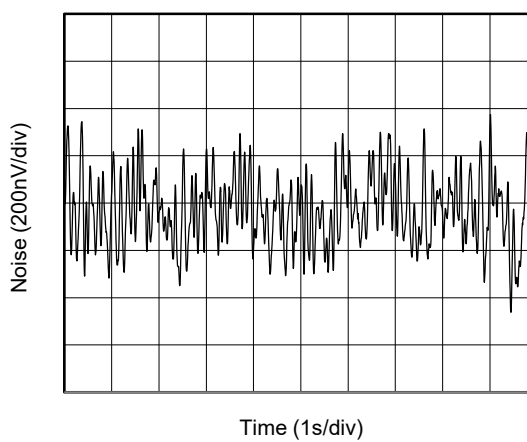
Negative Overload Recovery



Turn-On Time

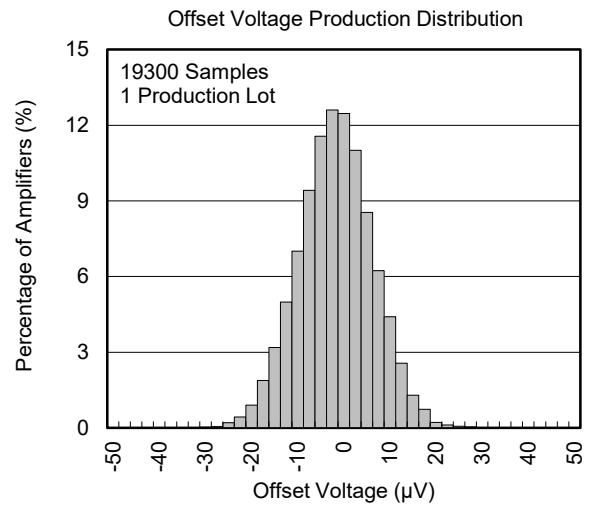
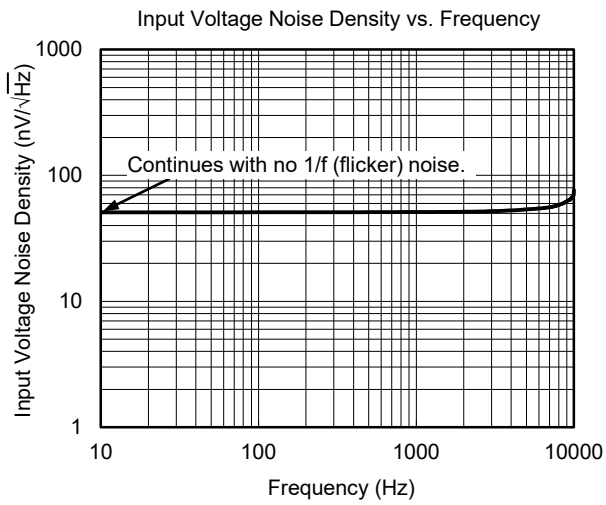


0.1Hz to 10Hz Noise



**TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A = +25^\circ\text{C}$ ,  $+V_S = 5\text{V}$ ,  $-V_S = 0\text{V}$ ,  $R_L = 10\text{k}\Omega$  and  $C_L = 0\text{pF}$ , unless otherwise noted.





**APPLICATION INFORMATION**

The SGM8250-1 and SGM8250-2 are unity-gain stable and free from unexpected output phase reversal. They provide low offset voltage and very low drift over time and temperature. For lowest offset voltage and precision performance, circuit layout and mechanical conditions should be optimized. Avoid temperature gradients that create thermoelectric (Seebeck) effects in the thermocouple junctions formed from connecting dissimilar conductors. These thermally-generated potentials can be made to cancel by ensuring they are equal on both input terminals. Other layout and design considerations include:

- Use low thermoelectric-coefficient conditions (avoid dissimilar metals).
- Thermally isolate components from power supplies or other heat sources.
- Shield operational amplifier and input circuitry from air currents, such as cooling fans.

Following these guidelines will reduce the likelihood of junctions being at different temperatures, which can cause thermoelectric voltages of 0.11µV/°C or higher, depending on materials used.

**Operating Voltage**

The SGM8250-1 and SGM8250-2 operational amplifiers operate over a power supply range of 3V to 24V (±1.5V to ±12V). Supply voltages higher than 26.4V (absolute maximum) can permanently damage the device.

**Input Voltage**

The SGM8250-1 and SGM8250-2 input common mode voltage range extends 0.1V beyond the supply rails. The SGM8250-1 and SGM8250-2 are designed to cover the full range without the troublesome transition region found in some other rail-to-rail amplifiers.

Normally, input bias current is about 80pA; however, input voltages exceeding the power supplies can cause excessive current flowing into or out of the input pins.

**Internal Offset Correction**

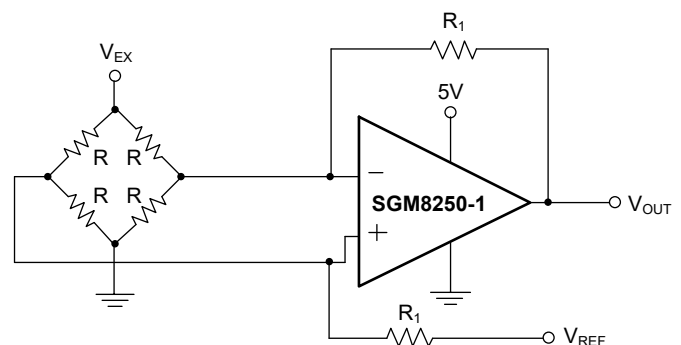
The SGM8250-1 and SGM8250-2 operational amplifiers use an auto-calibration technique to reduce internal offset. Upon power-up, the amplifier requires approximately 1.5ms to achieve specified  $V_{OS}$  accuracy.

**General Layout Guidelines**

Attention to good layout practices is always recommended. Keep traces short and, when possible, use a printed circuit board (PCB) ground plane with surface-mount components placed as close to the device pins as possible. Place a 0.1µF capacitor closely across the supply pins. These guidelines should be applied throughout the analog circuit to improve performance and provide benefits such as reducing the EMI (electromagnetic interference) susceptibility. Operational amplifiers vary in their susceptibility to radio frequency interference (RFI). RFI can generally be identified as a variation in offset voltage or DC signal levels with changes in the interfering RF signal. The SGM8250-1 and SGM8250-2 have been specifically designed to minimize susceptibility to RFI and demonstrate remarkably low sensitivity. Strong RF fields may still cause varying offset levels.

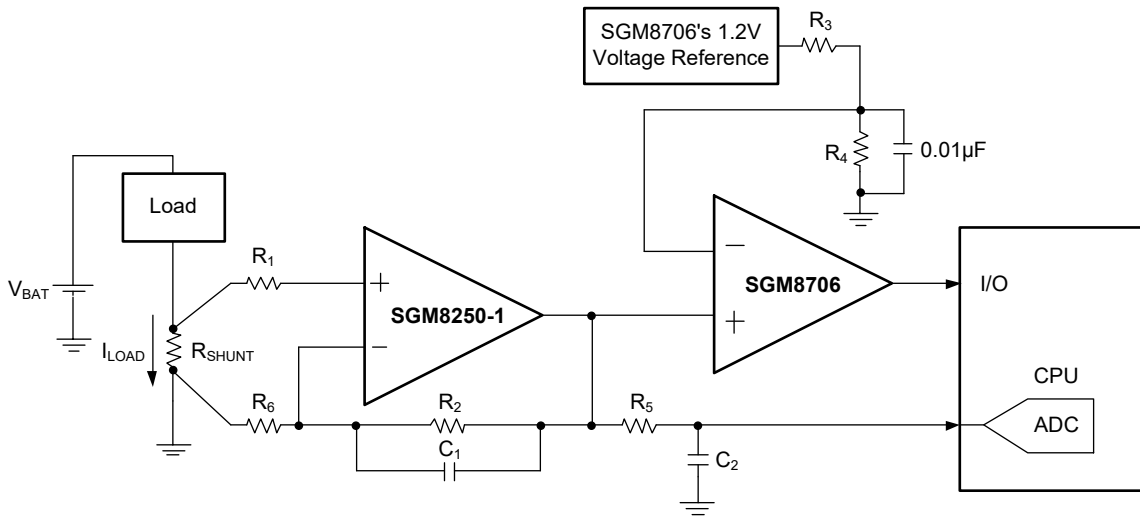
Figure 1 shows the basic configuration for a bridge amplifier.

A low-side current shunt monitor is shown in Figure 2.  $R_N$  are operational resistors used to isolate the ADC from the noise of the digital I<sup>2</sup>C bus. Since the ADC is a 16-bit converter, a precision reference is essential for maximum accuracy. Related application circuits are shown in Figure 3 ~ 5.

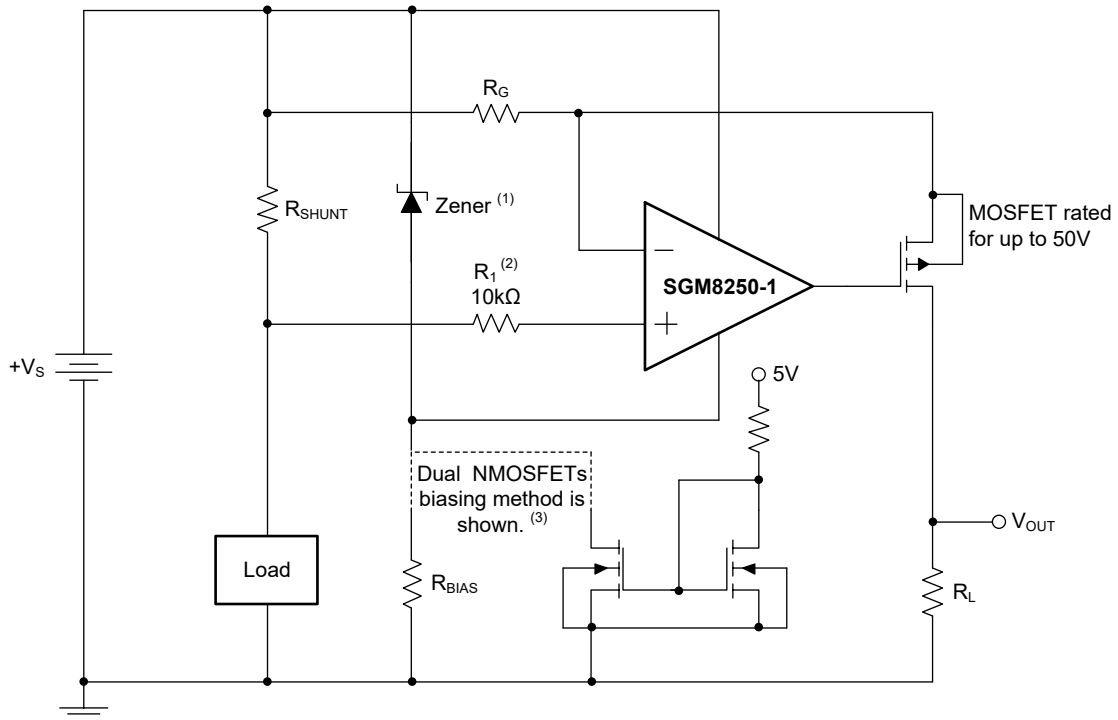


**Figure 1. Bridge Amplifier Configuration**

**APPLICATION INFORMATION (continued)**



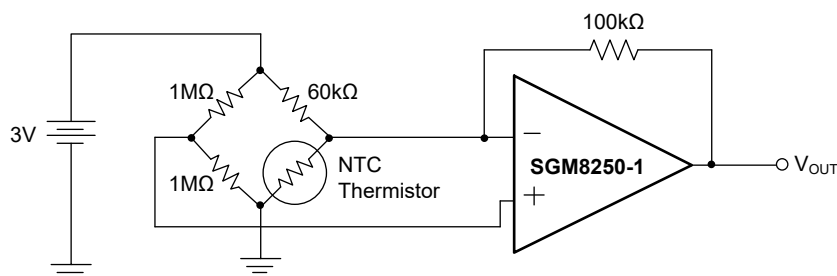
**Figure 2. Low-side Current Shunt Monitor**



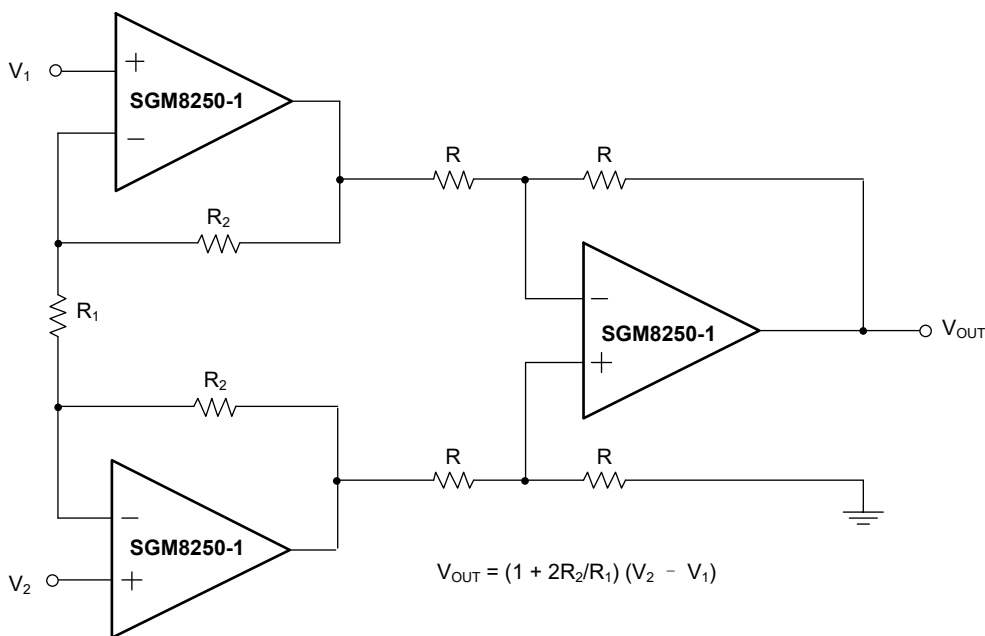
- NOTES: (1) Zener rated for operational amplifier supply capability (that is, 24V for SGM8250-1 and SGM8250-2).  
 (2) Current-limiting resistor.  
 (3) Choose Zener biasing resistor or dual NMOSFETs.

**Figure 3. High-side Current Shunt Monitor**

**APPLICATION INFORMATION (continued)**



**Figure 4. Thermistor Measurement**



**Figure 5. Precision Instrumentation Amplifier Configuration**

**REVISION HISTORY**

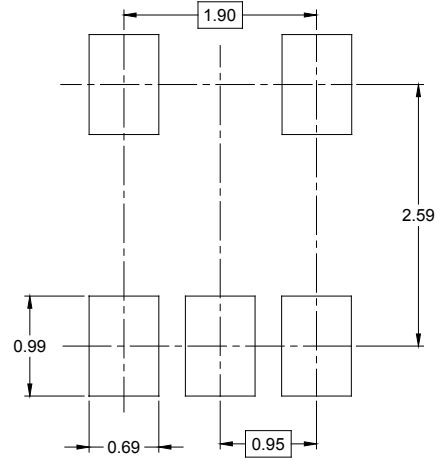
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

**Changes from Original (DECEMBER 2017) to REV.A**

Changed from product preview to production data.....	All
--	-----

PACKAGE OUTLINE DIMENSIONS

SOT-23-5



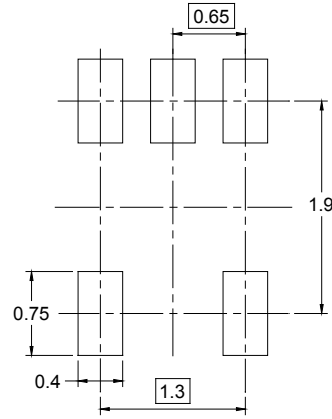
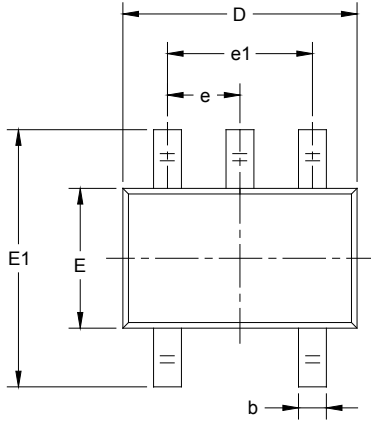
RECOMMENDED LAND PATTERN (Unit: mm)



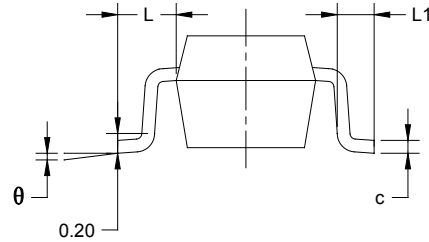
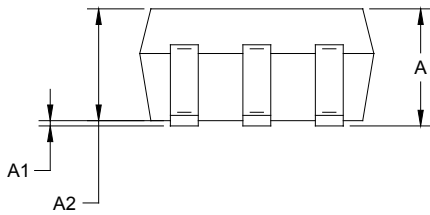
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.050	1.250	0.041	0.049
A1	0.000	0.100	0.000	0.004
A2	1.050	1.150	0.041	0.045
b	0.300	0.500	0.012	0.020
c	0.100	0.200	0.004	0.008
D	2.820	3.020	0.111	0.119
E	1.500	1.700	0.059	0.067
E1	2.650	2.950	0.104	0.116
e	0.950 BSC		0.037 BSC	
e1	1.900 BSC		0.075 BSC	
L	0.300	0.600	0.012	0.024
$\theta$	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

SC70-5



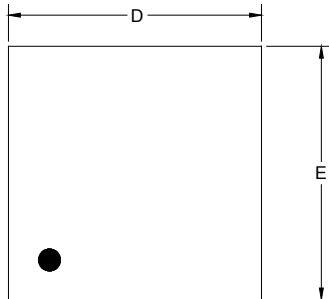
RECOMMENDED LAND PATTERN (Unit: mm)



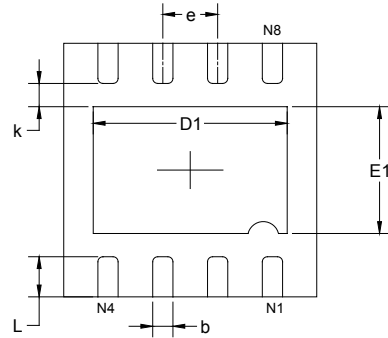
Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.900	1.100	0.035	0.043
A1	0.000	0.100	0.000	0.004
A2	0.900	1.000	0.035	0.039
b	0.150	0.350	0.006	0.014
c	0.080	0.150	0.003	0.006
D	2.000	2.200	0.079	0.087
E	1.150	1.350	0.045	0.053
E1	2.150	2.450	0.085	0.096
e	0.65 TYP		0.026 TYP	
e1	1.300 BSC		0.051 BSC	
L	0.525 REF		0.021 REF	
L1	0.260	0.460	0.010	0.018
$\theta$	0°	8°	0°	8°

PACKAGE OUTLINE DIMENSIONS

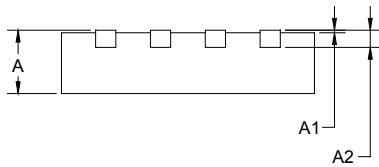
TDFN-3x3-8L



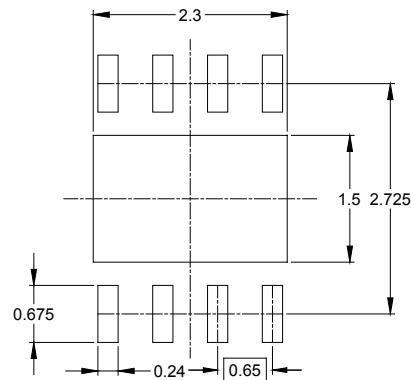
TOP VIEW



BOTTOM VIEW



SIDE VIEW

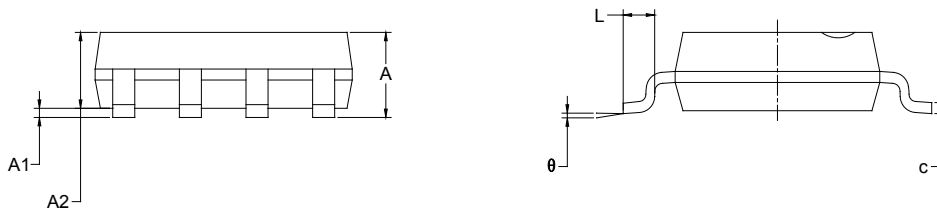
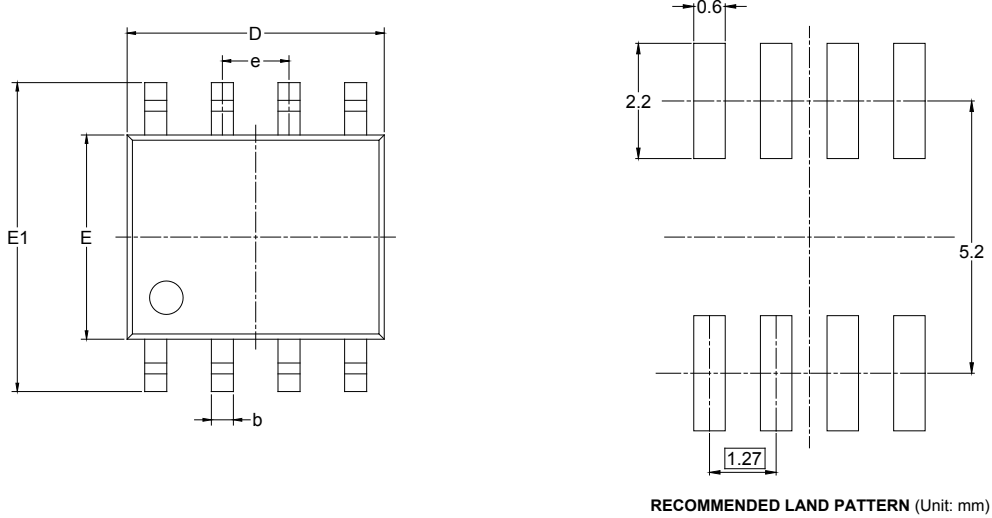


RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	0.700	0.800	0.028	0.031
A1	0.000	0.050	0.000	0.002
A2	0.203 REF		0.008 REF	
D	2.900	3.100	0.114	0.122
D1	2.200	2.400	0.087	0.094
E	2.900	3.100	0.114	0.122
E1	1.400	1.600	0.055	0.063
k	0.200 MIN		0.008 MIN	
b	0.180	0.300	0.007	0.012
e	0.650 TYP		0.026 TYP	
L	0.375	0.575	0.015	0.023

PACKAGE OUTLINE DIMENSIONS

SOIC-8



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	MIN	MAX	MIN	MAX
A	1.350	1.750	0.053	0.069
A1	0.100	0.250	0.004	0.010
A2	1.350	1.550	0.053	0.061
b	0.330	0.510	0.013	0.020
c	0.170	0.250	0.006	0.010
D	4.700	5.100	0.185	0.200
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.27 BSC		0.050 BSC	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

# PACKAGE INFORMATION

## TAPE AND REEL INFORMATION

### REEL DIMENSIONS



### TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

### KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
SOT-23-5	7"	9.5	3.20	3.20	1.40	4.0	4.0	2.0	8.0	Q3
SC70-5	7"	9.5	2.25	2.55	1.20	4.0	4.0	2.0	8.0	Q3
TDFN-3×3-8L	13"	12.4	3.35	3.35	1.13	4.0	8.0	2.0	12.0	Q1
SOIC-8	13"	12.4	6.40	5.40	2.10	4.0	8.0	2.0	12.0	Q1

DD0001



# PACKAGE INFORMATION

## CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

## KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5

DD0002